

Dual High-Speed CAN Transceiver with Standby Mode

Features

- Fully ISO 11898-2, ISO 11898-5, ISO 11898-2:2016, and SAE J2962-2 Compliant
- · CAN FD Ready
- · Communication Speed Up to 5 Mbps
- Low Electromagnetic Emission (EME) and High Electromagnetic Immunity (EMI)
- Differential Receiver with Wide Common-Mode Range
- Remote Wake-up Capability via CAN Bus Wake-up on Pattern (WUP) as Specified in ISO 11898-2:2016, 3.8 µs Activity Filter Time
- Functional Behavior Predictable Under All Supply Conditions
- Transceiver Disengages from the Bus when Not Powered Up
- RXD Recessive Clamping Detection
- High Electrostatic Discharge (ESD) Handling Capability on the Bus Pins
- Bus Pins Protected Against Transients in Automotive Environments
- Transmit Data (TXD) Dominant Time-out Function
- Undervoltage Detection on VCC Pin
- Bus Pins Short-Circuit and Overtemperature
 Protected
- Fulfills the OEM "Hardware Requirements for LIN, CAN and FlexRay™ Interfaces in Automotive Applications", Rev. 1.3
- Qualified According to AEC-Q100 and AEC-Q006
- Two Ambient Temperature Grades Available:
 - ATA6565-GCQW1 and ATA6565-GNQW1 Up to T_{amb} = +125°C
 - ATA6565-GCQW0 Up to T_{amb} = +150°C
- 14-Lead SOIC Package and 14-Lead VDFN Package with Wettable Flanks (Moisture Sensitivity Level 1)

Applications

Classical CAN and CAN FD networks in Automotive, Industrial, Aerospace, Medical and Consumer applications.

General Description

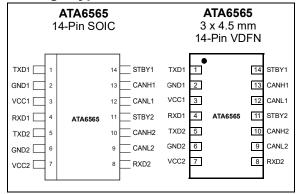
The ATA6565 is a fully integrated, dual high-speed Controller Area Network (CAN) transceiver with two completely independent and separated high-speed CAN transceivers integrated in one package (only the GND pins, GND1 and GND2, are internally connected). Each of the two identical transceivers provides an interface between a CAN protocol controller and a physical two-wire CAN bus.

The device is designed for high-speed (up to 5 Mbps) CAN applications in the automotive industry, providing differential transmit and receive capability to (a microcontroller with) a CAN protocol controller. It offers improved Electromagnetic Compatibility (EMC) and Electrostatic Discharge (ESD) performance, as well as features such as:

- Ideal passive behavior to the CAN bus when the supply voltage is off
- Very low current consumption in Standby mode with bus wake-up capability

Two operating modes, together with the dedicated fail-safe features, make the ATA6565 an excellent choice for all types of high-speed CAN networks. The ATA6565 includes more than one high-speed CAN interface, which requires a Low-Power mode with wake-up capability via the CAN bus. These features are especially valuable for body control units and gateways.

Package Types

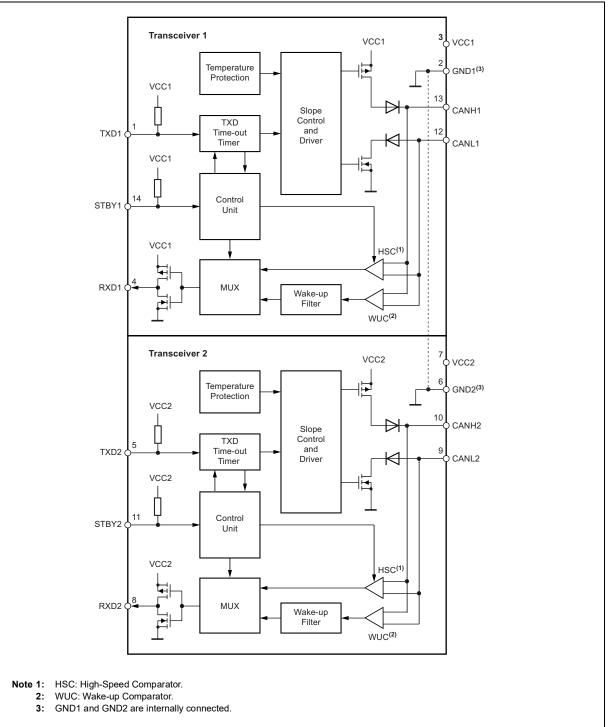


ATA6565 Family Members

Device	Grade 0	Grade 1	SOIC14	VDFN14
ATA6565-GNQW1		Х	Х	
ATA6565-GCQW1		Х		Х
ATA6565-GCQW0	Х			Х

Note: For ordering information, see the "Product Identification System" section.

Block Diagram



1.0 FUNCTIONAL DESCRIPTION

The ATA6565 is a stand-alone, dual high-speed CAN transceiver, compliant with the ISO 11898-2, ISO 11898-5, ISO 11898-2:2016, and SAE J2962-2 standards. Each of the two transceivers provides a very low current consumption in Standby mode and wake-up capability via the CAN bus.

The functions described in the following text apply to each of the two identical high-speed CAN transceivers integrated in the ATA6565. Therefore, if for example, the CANH pin is stated, this applies to each of the two transceivers, meaning CANH1 and CANH2. The two transceivers are identical, and there is no internal connection between them (with the exception of the GND pins, GND1 and GND2), so they work completely independent of each other.

1.1 Operating Modes

Each of the transceivers supports three operating modes: Unpowered, Standby, and Normal. Additionally, there is the internal Silent mode, which is not externally accessible. This mode is a Receive Only mode, which means the CAN drivers are deactivated and only data from the bus can be received.

The operating modes can be selected via the STBY pins (STBY1 and STBY2). See Figure 1-1 and Table 1-1 for a description of the operating modes.

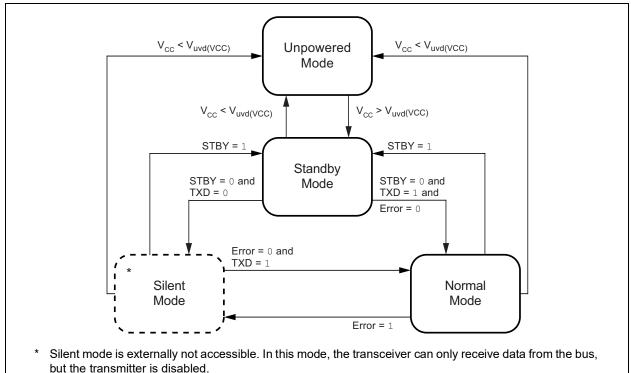


FIGURE 1-1: OPERATING MODES

TABLE 1-1:OPERATING MODES

Mada	Ing	outs	Outputs			
Mode	STBY	Pin TXD	CAN Driver	Pin RXD		
Unpowered	X ⁽¹⁾	X ⁽¹⁾	Recessive	Recessive		
Standby	High	X ⁽¹⁾	Recessive	Active ⁽²⁾		
Normal	Low	Low	Dominant	Low		
	Low	High	Recessive	High		

Note 1: Irrelevant.

2: Reflects the bus only for wake-up.

1.1.1 NORMAL MODE

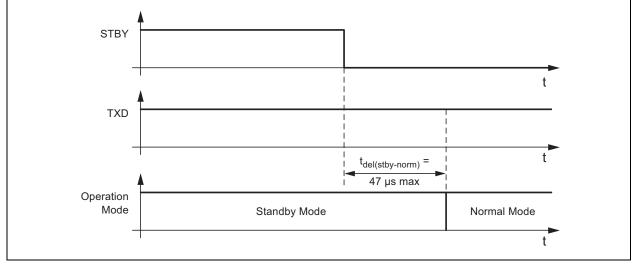
A low level on the STBY pin, together with a high level on the TXD pin, selects the Normal mode. In this mode, the transceiver is able to transmit and receive data via the CANH and CANL bus lines (see the **Block Diagram**). The output driver stage is active and drives data from the TXD input to the CAN bus. The High-Speed Comparator (HSC) converts the analog data on the bus lines into digital data, which is output to the RXD pin. The bus biasing is set to V_{VCC} /2 and the undervoltage monitoring of V_{VCC} is active.

The slope of the output signals on the bus lines is controlled and optimized in a way that ensures the lowest possible Electromagnetic Emission (EME). To switch the device to Normal operating mode, set the STBY pin to low and the TXD pin to high (see Table 1-1 and Figure 1-2). The STBY pin provides a pull-up resistor to VCC, thus ensuring a defined level if the pin is open.

Please note that the device cannot enter Normal mode as long as TXD is at ground level.

The switching into Normal mode is depicted in Figure 1-2.





1.1.2 STANDBY MODE

A high level on the STBY pin selects Standby mode. In this mode, the transceiver is not able to transmit or correctly receive data via the bus lines. The transmitter and the HSC are switched off to reduce current consumption.

1.1.2.1 Remote Wake-Up via CAN Bus

In Standby mode, the bus lines are biased to ground to reduce current consumption to a minimum. The device monitors the bus lines for a valid wake-up pattern, as specified in the ISO 11898-2:2016. This filtering helps to avoid spurious wake-up events that would be triggered by scenarios, such as a dominant clamped bus or a dominant phase due to noise, spikes on the bus, automotive transients, or EMI. The wake-up pattern consists of at least two consecutive dominant bus levels for a duration of at least t_{Filter} , each separated by a recessive bus level with a duration of at least t_{Filter} . Dominant or recessive bus levels shorter than t_{Filter} are always ignored. The complete dominant-recessive-dominant pattern, as shown in Figure 1-3, must be received within the bus wake-up time-out time, t_{Wake} , to be recognized as a valid wake-up pattern. Otherwise, the internal wake-up logic is reset and then the complete wake-up event. The RXD pin remains at a high level until a valid wake-up event has been detected.

During Normal mode, at a VCC undervoltage condition or when the complete wake-up pattern is not received within t_{Wake}, no wake-up is signaled at the RXD pin.

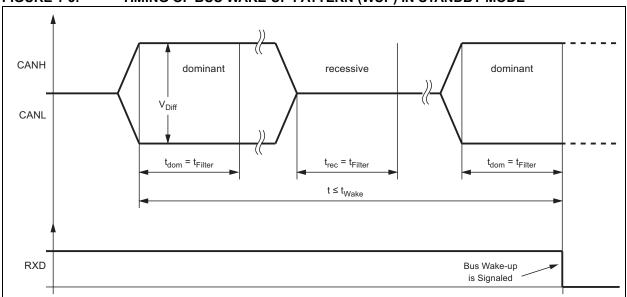


FIGURE 1-3: TIMING OF BUS WAKE-UP PATTERN (WUP) IN STANDBY MODE

When a valid CAN wake-up pattern is detected on the bus, the RXD pin switches to low to signal a wake-up request. A transition to Normal mode is not triggered until the STBY pin is forced back to low by the microcontroller.

1.2 Fail-Safe Features

1.2.1 TXD DOMINANT TIME-OUT FUNCTION

A TXD dominant time-out timer is started when the TXD pin is set to low. If the low state on the TXD pin persists for longer than $t_{to(dom)TXD}$, the transmitter is disabled, releasing the bus lines to the recessive state. This function prevents a hardware and/or software application

failure from driving the bus lines to a permanent dominant state (blocking all network communications). The TXD dominant time-out timer is reset when the TXD pin is set to high. If the low state on the TXD pin is longer than $t_{to(dom)TXD}$, then the TXD pin has to be set to high $\ge 4 \ \mu$ s in order to reset the TXD dominant time-out timer.

1.2.2 INTERNAL PULL-UP STRUCTURE AT TXD AND STBY INPUT PINS

The TXD and STBY pins have an internal pull-up to VCC. This ensures a safe, defined state in case one or both pins are left floating. Pull-up currents flow in these pins in all states, meaning all pins should be in a high state during Standby mode to minimize the current consumption.

1.2.3 UNDERVOLTAGE DETECTION ON VCC PIN

If V_{VCC} drops below its undervoltage detection level, $V_{uvd(VCC)}$ (see **Section 2.0 "Electrical Characteris-tics**"), the transceiver switches off and disengages from the bus until V_{VCC} has recovered. The low-power wake-up comparator is only switched off during a VCC undervoltage. The logic state of the STBY pin is ignored until the VCC voltage has recovered.

1.2.4 BUS WAKE-UP ONLY AT DEDICATED WAKE-UP PATTERN

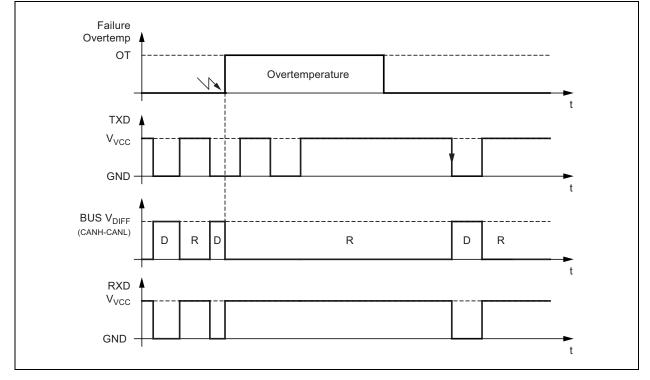
Due to the implementation of the wake-up filtering, the transceiver does not wake up when the bus is in a long dominant phase; it only wakes up at a dedicated wake-up pattern, as specified in the ISO 11898-2:2016. This means for a valid wake-up, at least two consecutive dominant bus levels for a duration of at least t_{Filter} , each separated by a recessive bus level with a duration of at

least t_{Filter} , must be received via the bus. Dominant or recessive bus levels shorter than t_{Filter} are always ignored. The complete dominant-recessive-dominant pattern, as shown in Figure 1-3, must be received within the bus wake-up time-out time, t_{Wake} , to be recognized as a valid wake-up pattern. This filtering leads to a higher robustness against EMI and transients, and therefore, significantly reduces the risk of an unwanted bus wake-up.

1.2.5 OVERTEMPERATURE PROTECTION

The output drivers are protected against overtemperature conditions. If the junction temperature exceeds the shutdown junction temperature, T_{Jsd} , the output drivers are disabled until the junction temperature drops below T_{Jsd} and the TXD pin is at a high level again. This TXD condition ensures that output driver oscillations, due to temperature drift, are avoided.





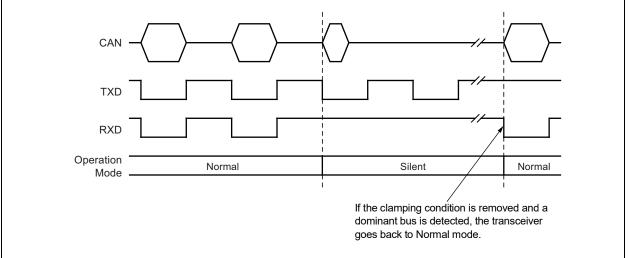
1.2.6 SHORT-CIRCUIT PROTECTION OF BUS PINS

The CANH and CANL bus outputs are short-circuit protected, either against GND or a positive supply voltage. A current-limiting circuit protects the transceiver against damage. If the device is heating up due to a continuous short on CANH or CANL, the internal overtemperature protection switches the bus transmitter off.

1.2.7 RXD RECESSIVE CLAMPING

This fail-safe feature prevents the controller from sending data on the bus if its RXD is clamped to high (for example, recessive). That is, if the RXD pin cannot signal a dominant bus condition (for example, because it is shorted to VCC), the transmitter is disabled to avoid possible data collisions on the bus. In Normal mode, the device permanently compares the state of the HSC with the state of the RXD pin. If the HSC indicates a dominant bus state for more than t_{RC_det} , without the RXD pin doing the same, a recessive clamping situation is detected and the transceiver is forced into Silent mode. This Fail-Safe mode is released by either entering Standby or Unpowered mode, or if the RXD pin is showing a dominant (for example, low) level again.





1.3 Pin Description

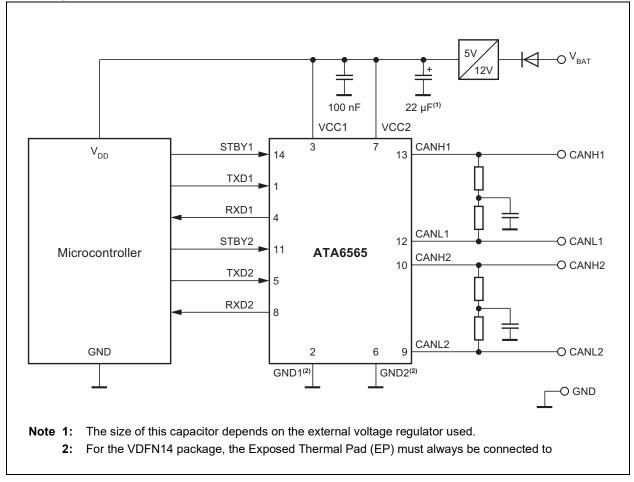
The descriptions of the pins are listed in Table 1-2.

Pin Number	Pin Name	Description				
1	TXD1	Transmit Data Input 1				
2	GND1	Ground 1, Internally Connected to GND2				
3	VCC1	Supply Voltage of Transceiver 1				
4	RXD1	Receive Data Output 1; Reads out Data from the Bus Lines of Transceiver 1				
5	TXD2	Transmit Data Input 2				
6	GND2	Ground 2, Internally Connected to GND1				
7	VCC2	Supply Voltage of Transceiver 2				
8	RXD2	Receive Data Output 2; Reads out Data from the Bus Lines of Transceiver 2				
9	CANL2	Low-Level CAN Bus Line 2				
10	CANH2	High-Level CAN Bus Line 2				
11	STBY2	Standby Mode Control Input of Transceiver 2				
12	CANL1	Low-Level CAN Bus Line 1				
13	CANH1	High-Level CAN Bus Line 1				
14	STBY1	Standby Mode Control Input of Transceiver 1				
15	EP ⁽¹⁾	Exposed Thermal Pad: Heat Slug, Internally Connected to the GND Pins				

TABLE 1-2: PIN FUNCTION TABLE

Note 1: Only for the VDFN package.

1.4 Typical Application



NOTES:

2.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings^(†)

DC Voltage at CANH1, CANL1, CANH2, CANL2 (V _{CANH} , V _{CANL})27 to +42V	
Transient Voltage at CANH, CANL (according to ISO 7637, Part 2) (V _{CANH} , V _{CANL})150 to +100V	
Max. Differential Bus Voltage (V _{Diff})–5 to +18V	
DC Voltage on All Other Pins (V _X)–0.3 to +5.5V	
ESD according to IBEE CAN EMC – Test Specification following	
IEC 61000-4-2 – Pins CANH1, CANL1, CANH2, CANL2±8 kV	
ESD (HBM following STM5.1 with 1.5 k Ω /100 pF) – Pins CANH1, CANL1, CANH2, CANL2 to GND±6 kV	
Component Level ESD (HBM according to ANSI/ESD STM5.1, JESD22-A114, AEC-Q100 (002)±4 kV	
CDM ESD STM 5.3.1±750V	
ESD Machine Model AEC-Q100-RevF(003)±200V	
Virtual Junction Temperature (T _{vJ})40°C to +175°C	
Storage Temperature Range (T _{stg})–55°C to +150°C	

† Notice:Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 2-1: ELECTRICAL CHARACTERISTICS

Electrical Specifications: The values below are valid for each of the two identical integrated CAN transceivers. Grade 1: $T_{amb} = -40^{\circ}C$ to $+125^{\circ}C$ and Grade 0: $T_{amb} = -40^{\circ}C$ to $+150^{\circ}C$; $T_{vJ} \le +170^{\circ}C$; $V_{VCC} = 4.5V$ to 5.5V; $R_{L} = 60\Omega$; $C_{L} = 100 \text{ pF}$ unless specified otherwise; all voltages are defined in relation to ground; positive currents flow into the IC.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions				
Supply, Pin VCC										
Supply Voltage	V _{VCC}	4.5	_	5.5	V					
Supply Current in Silent Mode	I _{VCC_sil}	1.9	2.5	3.2	mA	Silent mode, V _{TXD} = V _{VCC}				
	I _{VCC_rec}	2	_	5	mA	Recessive, V _{TXD} = V _{VCC}				
Supply Current in Normal	I _{VCC_dom}	30	50	70	mA	Dominant, V _{TXD} = 0V				
Mode	I _{VCC_short}	_	—	85	mA	Short between CANH and CANL (Note 1)				
Supply Current in Standby	I _{VCC_STBY}	—	_	12	μA	V _{TXD} = V _{VCC}				
Mode	I _{VCC_STBY}	—	7	—	μA	T _{amb} = +25°C (Note 3)				
Undervoltage Detection Threshold on Pin VCC	V _{uvd(VCC)}	2.75		4.5	V	_				
Mode Control Input, Pin S	STBY									
High-Level Input Voltage	V _{IH}	$0.7 \times V_{VCC}$		V _{VCC} + 0.3	V					
Low-Level Input Voltage	V _{IL}	-0.3		$0.3 \times V_{VCC}$	V	—				
Pull-up Resistor to VCC	R _{pu}	75	125	175	kΩ	V _{STBY} = 0V				
High-Level Leakage Current	IL	-2	_	+2	μA	V _{STBY} = V _{VCC}				

Note 1: 100% correlation tested.

2: Characterized on samples.

3: Design parameter.

Electrical Specifications: The values below are valid for each of the two identical integrated CAN transceivers. Grade 1: $T_{amb} = -40^{\circ}$ C to +125°C and Grade 0: $T_{amb} = -40^{\circ}$ C to +150°C; $T_{vJ} \le +170^{\circ}$ C; $V_{VCC} = 4.5$ V to 5.5V; $R_{L} = 60\Omega$; $C_{L} = 100 \text{ pF}$ unless specified otherwise; all voltages are defined in relation to ground; positive currents flow into the IC.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
CAN Transmit Data Input	-		.46.	indx.	51113	
		07.41		V +02	V	
High-Level Input Voltage Low-Level Input Voltage	V _{IH}	$\begin{array}{c} 0.7 \times V_{VCC} \\ -0.3 \end{array}$		$V_{VCC} + 0.3$	V	
Pull-up Resistor to VCC		_0.3 20	35	$0.3 \times V_{VCC}$ 50	v kΩ	<u> </u>
•	R _{TXD}	20		50	K12	V _{TXD} = 0V
High-Level Leakage Current	I _{TXD}	-2	—	+2	μA	Normal mode, V _{TXD} = V _{VCC}
Input Capacitance	C _{TXD}		5	10	pF	(Note 3)
CAN Receive Data Outpu	t, Pin RXD	1		r — — — — — — — — — — — — — — — — — — —		
High-Level Output Cur- rent	I _{OH}	-8	_	-1	mA	Normal mode, V _{RXD} = V _{VCC} – 0.4V
Low-Level Output Cur- rent, Bus Dominant	I _{OL}	2	_	12	mA	Normal mode, V _{RXD} = 0.4V
Bus Lines, Pins CANH ar	nd CANL					•
Single-Ended Dominant	Varia	2.75	3.5	4.5	V	$V_{TXD} = 0V, t < t_{to(dom)TXD},$ $R_L = 50W to 65W,$ CANH pin (Note 1)
Output Voltage	V _{O(dom)}	0.5	1.5	2.25	V	$V_{TXD} = 0V$, t < t _{to(dom)TXD} , R _L = 50W to 65W, CANL pin (Note 1)
Transmitter Voltage Symmetry	V _{Sym}	0.9	1.0	1.1	_	
		1.5	_	3	V	V_{TXD} = 0V, t < t _{to(dom)TXD} , R _L = 45 Ω to 65 Ω
		1.5		3.3	V	R _L = 70Ω (Note 3)
		1.5		5	V	R _L = 2240Ω (Note 3)
Bus Differential Output Voltage	V _{Diff}	-50	_	+50	mV	Normal and Silent mode, $V_{VCC} = 4.75V$ to 5.25V, $V_{TXD} = V_{VCC}$, recessive, no load
		-200		+200	mV	Standby mode: $V_{VCC} = 4.75V$ to 5.25V $V_{TXD} = V_{VCC}$, recessive, no load
Single-Ended Recessive	V _{O(rec)}	2	$0.5 imes V_{VCC}$	3	V	Normal and Silent mode, V _{TXD} = V _{VCC} , no load
Output Voltage	V _{O(rec)}	-0.1		+0.1	V	Standby mode, V _{TXD} = V _{VCC} , no load
Differential Receiver	V _{th(RX)dif}	0.5	0.7	0.9	V	Normal and Silent mode (HSC), $V_{cm(CAN)} = -27V$ to +27V
Threshold Voltage	V _{th(RX)dif}	0.4	0.7	1.1	V	Standby mode (WUC), V _{cm(CAN)} = -27V to +27V (Note 1)

Note 1: 100% correlation tested.

- 2: Characterized on samples.
- **3:** Design parameter.

Electrical Specifications: The values below are valid for each of the two identical integrated CAN transceivers. Grade 1: $T_{amb} = -40^{\circ}$ C to +125°C and Grade 0: $T_{amb} = -40^{\circ}$ C to +150°C; $T_{vJ} \le +170^{\circ}$ C; $V_{VCC} = 4.5$ V to 5.5V; $R_L = 60\Omega$; $C_L = 100 \text{ pF}$ unless specified otherwise; all voltages are defined in relation to ground; positive currents flow into the IC.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Differential Receiver Hysteresis Voltage	V _{hys(RX)dif}	50	120	200	mV	Normal and Silent mode (HSC), V _{cm(CAN)} = –27V to +27V
Dominant Output Current	lie (r. s.	-75	_	-35	mA	$ \begin{array}{l} V_{TXD} = 0V, t < t_{to(dom)TXD}, \\ V_{VCC} = 5V, CANH pin, \\ V_{CANH} = -5V \end{array} $
	I _{IO(dom)}	35	_	75	mA	$ \begin{array}{l} V_{TXD} = 0V, t < t_{to(dom)TXD}, \\ V_{VCC} = 5V, CANL pin, \\ V_{CANL} = +40V \end{array} $
Recessive Output Current	I _{IO(rec)}	-5	_	+5	mA	Normal and Silent mode, $V_{TXD} = V_{VCC}$, no load, $V_{CANH} = V_{CANL} = -27V$ to +32V
	I _{IO(leak)}	-5	0	+5	μA	$V_{VCC} = 0V,$ $V_{CANH} = V_{CANL} = 5V$
Leakage Current	I _{IO(leak)}	-5	0	+5	μA	VCC is connected to GND with R = $47k\Omega$, V _{CANH} = V _{CANL} = 5V (Note 3)
	R _i	9	15	28	kΩ	V _{CANH} = V _{CANL} = 4V
Input Resistance	R _i	9	15	28	kΩ	–2V ≤ V _{CANH} ≤ +7V, –2V ≤ V _{CANL} ≤ +7V (Note 3)
Input Resistance Devia-	ΔR_i	-1	0	+1	%	Between CANH and CANL, V _{CANH} = V _{CANL} = 4V
tion	ΔR _i	-1	0	+1	%	Between CANH and CANL, $-2V \le V_{CANH} \le +7V$, $-2V \le V_{CANL} \le +7V$ (Note 3)
Differential Input Resis-	R _{i(dif)}	18	30	56	kΩ	V _{CANH} = V _{CANL} = 4V
tance	R _{i(dif)}	18	30	56	kΩ	–2V ≤ V _{CANH} ≤ +7V, –2V ≤ V _{CANL} ≤ +7V (Note 3)
Common-Mode Input Capacitance	C _{i(cm)}		_	20	pF	f = 500 kHz, CANH and CANL referred to GND (Note 3)
Differential Input Capacitance	C _{i(dif)}	_	—	10	pF	f = 500 kHz, between CANH and CANL (Note 3)
Differential Bus Voltage Range for Recessive	V _{Diff_rec}	-3	_	+0.5	V	Normal and Silent mode (HSC), $-27V \le V_{CANH} \le +27V$, $-27V \le V_{CANL} \le +27V$ (Note 3)
State Detection	V _{Diff_rec}	-3	_	+0.4	V	Standby mode (WUC) -27V ≤ V _{CANH} ≤ +27V, -27V ≤ V _{CANL} ≤ +27V (Note 3)
Differential Bus Voltage Range for Dominant State	V_{Diff_dom}	0.9	_	8.0	V	Normal and Silent mode (HSC), $-27V \le V_{CANH} \le +27V$, $-27V \le V_{CANL} \le +27V$ (Note 3)
Detection	V_{Diff_dom}	1.15	_	8.0	V	Standby mode (WUC), –27V ≤ V _{CANH} ≤ +27V, –27V ≤ V _{CANL} ≤ +27V (Note 3)

Note 1: 100% correlation tested.

2: Characterized on samples.

3: Design parameter.

Electrical Specifications: The values below are valid for each of the two identical integrated CAN transceivers. Grade 1: $T_{amb} = -40^{\circ}$ C to +125°C and Grade 0: $T_{amb} = -40^{\circ}$ C to +150°C; $T_{vJ} \le +170^{\circ}$ C; $V_{VCC} = 4.5$ V to 5.5V; $R_{L} = 60\Omega$; $C_{L} = 100 \text{ pF}$ unless specified otherwise; all voltages are defined in relation to ground; positive currents flow into the IC.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions			
Transceiver Timing, Pins	CANH, CANI	, TXD and	RXD (see	Figure 2-1 a	nd <mark>Fig</mark>	ure 2-3)			
Delay Time from TXD to Bus Dominant	t _{d(TXD-bus-} dom)	40	—	130	ns	Normal mode (Note 2)			
Delay Time from TXD to Bus Recessive	t _{d(TXD-busrec)}	40		130	ns	Normal mode (Note 2)			
Delay Time from Bus Dominant to RXD	t _{d(bus-} dom-RXD)	20		100	ns	Normal mode (Note 2)			
Delay Time from Bus Recessive to RXD	t _{d(busrec-RXD)}	20	_	100	ns	Normal mode (Note 2)			
		40	_	210	ns	Normal mode, rising edge at TXD pin, $R_L = 60\Omega$, $C_L = 100 \text{ pF}$			
	^t PD(TXD-RXD)	40	_	200	ns	Normal mode, falling edge at TXD pin, $R_L = 60\Omega$, $C_L = 100 \text{ pF}$			
Propagation Delay from TXD to RXD	^t PD(TXD-RXD)	_	_	300	ns	Normal mode, rising edge at TXD pin, $R_L = 150\Omega$, $C_L = 100 \text{ pF}$ (Note 3)			
		_	—	300	ns	Normal mode, falling edge at TXD pin, R _L = 150Ω, C _L = 100pF (Note 3)			
TXD Dominant Time-out Time	t _{to(dom)TXD}	0.8	_	3	ms	V _{TXD} = 0V, Normal mode			
Bus Wake-up Time-out Time	t _{Wake}	0.8		3	ms	Standby mode (Note 1)			
Min. Dominant/Recessive Bus Wake-up Time	t _{Filter}	0.5	3	3.8	μs	Standby mode			
Delay Time for Standby Mode to Normal Mode Transition	t _{del(stby-norm)}	_	_	47	μs	Falling edge at STBY pin			
Delay Time for Normal Mode to Standby Mode Transition	t _{del(norm-stby)}	_	_	5	μs	Rising edge at STBY pin (Note 3)			

Note 1: 100% correlation tested.

2: Characterized on samples.

3: Design parameter.

Electrical Specifications: The values below are valid for each of the two identical integrated CAN transceivers. Grade 1: $T_{amb} = -40^{\circ}$ C to +125°C and Grade 0: $T_{amb} = -40^{\circ}$ C to +150°C; $T_{vJ} \le +170^{\circ}$ C; $V_{VCC} = 4.5$ V to 5.5V; $R_{L} = 60\Omega$; $C_{L} = 100 \text{ pF}$ unless specified otherwise; all voltages are defined in relation to ground; positive currents flow into the IC.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions				
Transceiver Timing for Higher Bit Rates, Pins CANH, CANL, TXD and RXD (see Figure 2-1 and Figure 2-3)										
Debouncing Time for Recessive Clamping State Detection	t _{RC_det}	_	_	90	ns	V _(CANH-CANL) > 900 mV, RXD = high (Note 3)				
Recessive Bit Time on RXD	t _{Bit(RXD)}	400	—	550	ns	Normal mode, t _{Bit(TXD)} = 500 ns (Note 1)				
RAD	· · · ·	120	—	220	ns	Normal mode, t _{Bit(TXD)} = 200 ns				
Recessive Bit Time on the Bus	t _{Bit(Bus)}	435	—	530	ns	Normal mode, t _{Bit(TXD)} = 500 ns (Note 1)				
Dus		155	—	210	ns	Normal mode, t _{Bit(TXD)} = 200 ns				
Receiver Timing	∆t _{Rec}	-65	_	+40	ns	Normal mode, $t_{Bit(TXD)} = 500 \text{ ns}$, $\Delta t_{Rec} = t_{Bit(RXD)} - t_{Bit(Bus)}$ (Note 1)				
Symmetry	Rec	-45		+15	ns	Normal mode, $t_{Bit(TXD)} = 200 \text{ ns}$, $\Delta t_{Rec} = t_{Bit(RXD)} - t_{Bit(Bus)}$				

Note 1: 100% correlation tested.

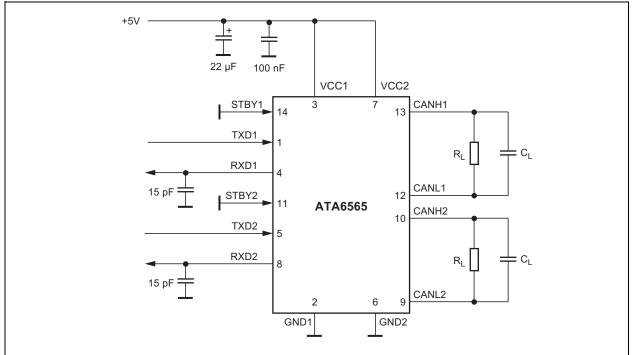
2: Characterized on samples.

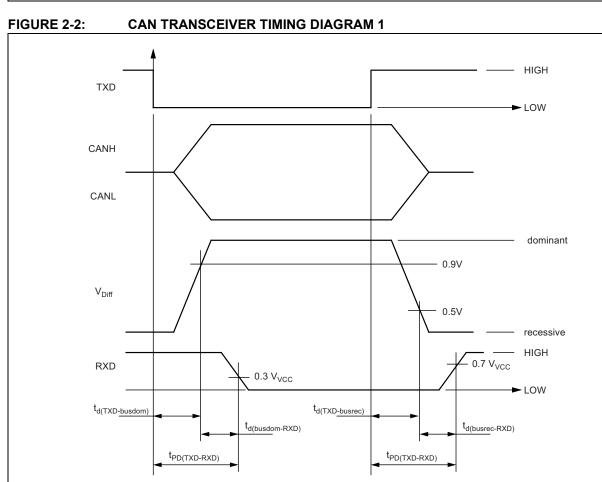
3: Design parameter.

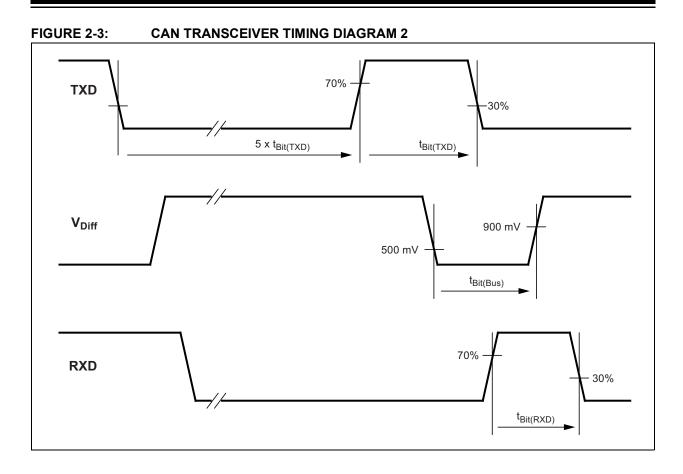
TABLE 2-2: TEMPERATURE SPECIFICATIONS

Parameters	Sym.	Min.	Тур.	Max.	Units
14-Lead SOIC					
Thermal Shutdown of the Bus Drivers for ATA6565-GNQW1 (Grade 1)	T _{vJsd}	150	—	195	°C
Thermal Shutdown Hysteresis	T _{vJsd_hys}	_	15	—	°C
Thermal Resistance Virtual Junction to Ambient, Where IC is Soldered to PCB according to JEDEC	R _{thvJA}	—	110	—	K/W
14-Lead VDFN					
Thermal Shutdown of the Bus Drivers for ATA6565-GCQW1 (Grade 1)	T _{vJsd}	150	_	195	°C
Thermal Shutdown of the Bus Drivers for ATA6565-GCQW0 (Grade 0)	T _{vJsd}	170	_	195	°C
Thermal Shutdown Hysteresis	T _{vJsd_hys}		15	_	°C
Thermal Resistance Virtual Junction to Heat Slug	R _{thvJC}		8	—	K/W
Thermal Resistance Virtual Junction to Ambient, Where Heat Slug is Soldered to PCB according to JEDEC	R _{thvJA}	_	45	_	K/W





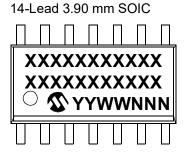




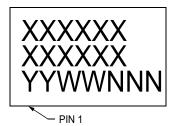
NOTES:

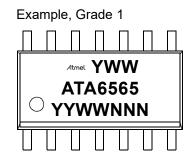
3.0 PACKAGING INFORMATION

Package Marking Information

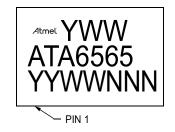


14-Lead 4.5 x 3 mm VDFN

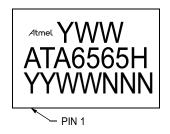




Example, Grade 1



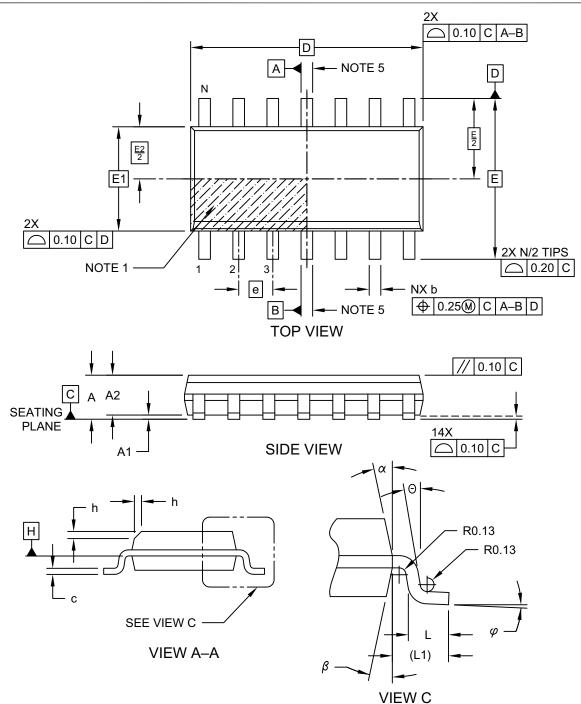
Example, Grade 0



Legend	: XXX Y YY WW NNN (©3) *	Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
	be carried	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

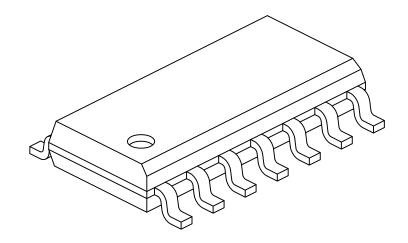
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-065-SL Rev D Sheet 1 of 2

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS						
Dimension	MIN	NOM	MAX				
Number of Pins	N		14				
Pitch	е		1.27 BSC				
Overall Height	Α	-	-	1.75			
Molded Package Thickness	A2	1.25	-	-			
Standoff §	A1	0.10	-	0.25			
Overall Width	E		6.00 BSC				
Molded Package Width	Molded Package Width E1			3.90 BSC			
Overall Length	D		8.65 BSC				
Chamfer (Optional)	h	0.25	-	0.50			
Foot Length	L	0.40	-	1.27			
Footprint	L1	1.04 REF					
Lead Angle	Θ	0°	-	-			
Foot Angle	φ	0°	-	8°			
Lead Thickness	С	0.10	-	0.25			
Lead Width	b	0.31	-	0.51			
Mold Draft Angle Top	α	5°	-	15°			
Mold Draft Angle Bottom	β	5°	-	15°			

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

- Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
- Dimensioning and tolerancing per ASME Y14.5M BSC: Basic Dimension. Theoretically exact value shown without tolerances.

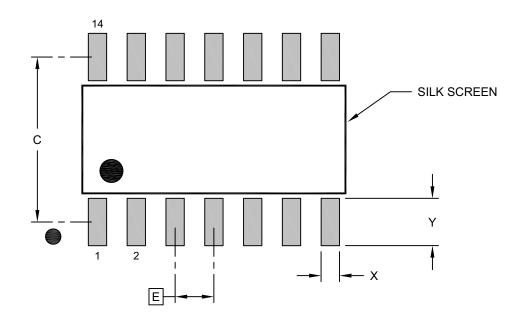
REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-065-SL Rev D Sheet 2 of 2

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X14)	Х			0.60
Contact Pad Length (X14)	Y			1.55

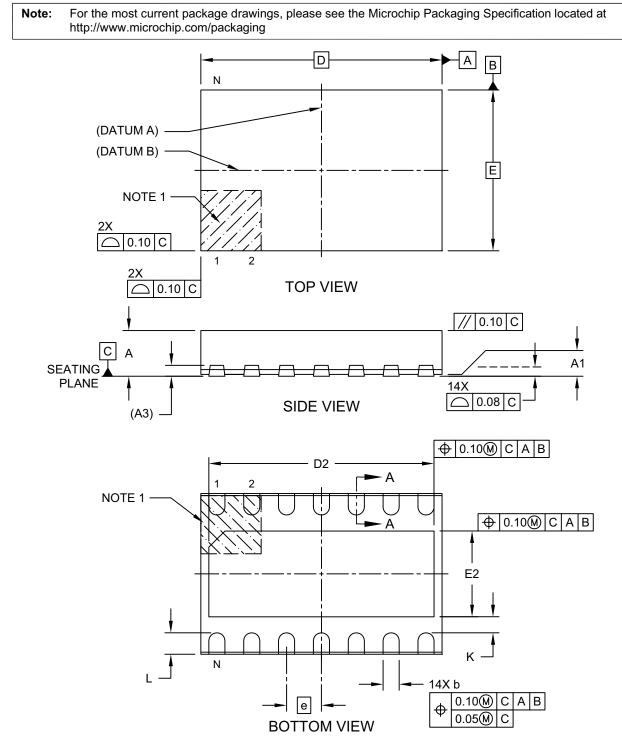
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2065-SL Rev D

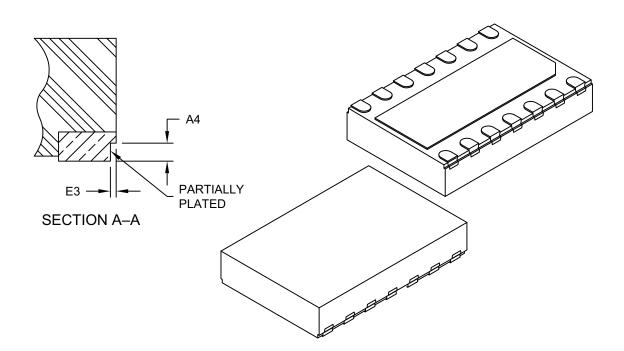
14-Lead Very Thin Plastic Dual Flat, No Lead Package (QBB) - 4.5x3 mm Body [VDFN] With 1.6x4.2 mm Exposed Pad and Stepped Wettable Flanks



Microchip Technology Drawing C04-21361 Rev C Sheet 1 of 2

14-Lead Very Thin Plastic Dual Flat, No Lead Package (QBB) - 4.5x3 mm Body [VDFN] With 1.6x4.2 mm Exposed Pad and Stepped Wettable Flanks

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimensior	MIN	NOM	MAX		
Number of Terminals	Ν	14			
Pitch	е	0.65 BSC			
Overall Height	Α	0.80	0.90	1.00	
Standoff	A1	0.00	0.03	0.05	
Terminal Thickness	A3	0.203 REF			
Overall Length	D	4.50 BSC			
Exposed Pad Length	D2	4.15	4.20	4.25	
Overall Width	E	3.00 BSC			
Exposed Pad Width	E2	1.50	1.50 1.60		
Terminal Width	b	0.27	0.27 0.32		
Terminal Length	L	0.35	0.40	0.45	
Terminal-to-Exposed-Pad	K	0.20 -		-	
Wettable Flank Step Cut Depth	A4	0.10	-	0.19	
Wettable Flank Step Cut Width	E3	-	-	0.085	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

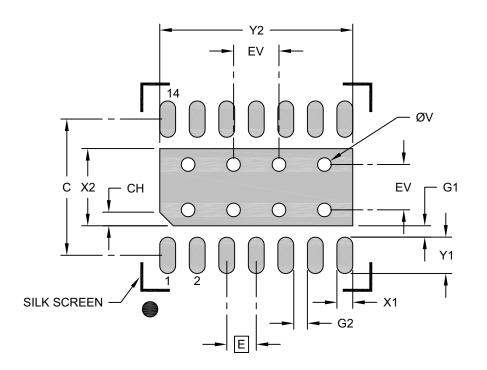
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-21361 Rev C Sheet 2 of 2

14-Lead Very Thin Plastic Dual Flat, No Lead Package (QBB) - 4.5x3 mm Body [VDFN] With 1.6x4.2 mm Exposed Pad and Stepped Wettable Flanks

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS				
Dimension	MIN	NOM	MAX		
Contact Pitch	E	0.65 BSC			
Optional Center Pad Width	X2	1			
Optional Center Pad Length	Y2			4.25	
Contact Pad Spacing	С		3.00		
Contact Pad Width (X14)	X1			0.35	
Contact Pad Length (X14)	Y1			0.80	
Pin 1 Index Chamfer	СН		0.30		
Contact Pad to Center Pad (X14)	G1	0.20			
Contact Pad to Center Pad (X12)	G2	0.20			
Thermal Via Diameter	V		0.30		
Thermal Via Pitch	EV		1.00		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-23361 Rev C

NOTES:

APPENDIX A: REVISION HISTORY

Revision E (July 2020)

The following is the list of modifications:

- Updated Features.
- Updated the Supply Current in Silent Mode parameter in TABLE 2-1: Electrical Characteristics.
- Added test conditions for several parameters in TABLE 2-1: Electrical Characteristics.
- Added the Bus Differential Output Voltage in Standby mode parameter in TABLE 2-1: Electrical Characteristics.
- Minor typographical edits.

Revision D (September 2019)

The following is the list of modifications:

• Updated TABLE 2-2: Temperature Specifications.

Revision C (July 2019)

The following is the list of modifications:

- Updated the Features section.
- · Updated the ATA6565 Family Members section.
- Added test conditions for the Input Capacitance parameter in TABLE 2-1: Electrical Characteristics.
- Updated TABLE 2-2: Temperature Specifications.
- · Updated the Product Identification System.

Revision B (September 2017)

The following is the list of modifications:

- Added the new devices ATA6565-GNQW0 and ATA656- GNQW1 and updated the related information across the document.
- Updated the Package Types section.
- Updated ATA6565 Family Members section.
- Modified Figure 1-3.
- Updated Section 1.3, Pin Description.
- Updated TABLE 2-2: Temperature Specifications.
- Updated Section 3.0, Packaging Information.
- · Updated the Product Identification System.
- · Fixed minor typographical errors.

Revision A (June 2017)

- Original Release of this Document.
- This document replaces Atmel 9364G-11/16.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

			Examples:					
PART NO.	XX Package	Tape and Reel Option	X Package Directives Classification	X Temperature Range	a)	ATA6	6565-GCQW0:	ATA6565, 14-Lead VDFN, Tape and Reel, Package according to RoHS, Temperature Grade 0
Device:	ATA6	J	Speed CAN Transceive	er with	b)	ATA6	565-GCQW1:	ATA6565, 14-Lead VDFN, Tape and Reel, Package according to RoHS, Temperature Grade 1
Package:	GC =	Standby M 14-Lead VDFN	lode		c)	ATA6	565-GNQW1:	ATA6565, 14-Lead SOIC, Tape and Reel, Package according to RoHS, Temperature Grade 1
	GN =	14-Lead SOIC						Temperature Grade T
Tape and Reel Option:		330 mm diameter Package accordin			No	te 1:	catalog part nu used for orderi the device pac	identifier only appears in the mber description. This identifier is ng purposes and is not printed on kage. Check with your Microchip r package availability with the Tape n.
Package Directives Classification:		Package accordin	g to kohs			2:	0.09% (900 pp (CI), and less t	nt, maximum concentration value of m) for Bromine (Br) and Chlorine han 0.15% (1500 ppm) total nd Chlorine (Cl) in any
Temperature Range:			le 0 (-40°C to +150°C) le 1 (-40°C to +125°C)				homogeneous	material. Maximum concentration (900 ppm) for Antimony (Sb) in

NOTES:

Note the following details of the code protection feature on Microchip devices:

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